

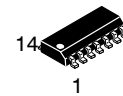
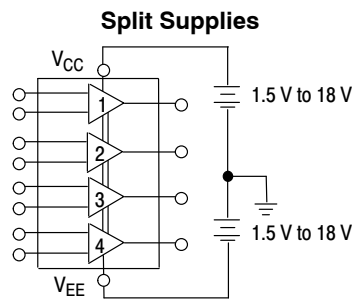
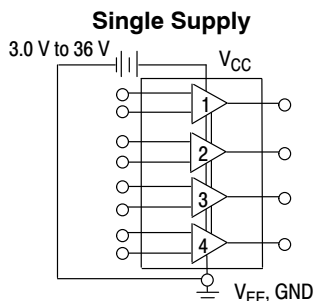
Single Supply Quad Operational Amplifiers

MC3403, MC3303

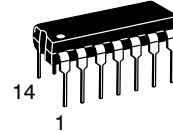
The MC3403 is a low cost, quad operational amplifier with true differential inputs. The device has electrical characteristics similar to the popular MC1741C. However, the MC3403 has several distinct advantages over standard operational amplifier types in single supply applications. The quad amplifier can operate at supply voltages as low as 3.0 V or as high as 36 V with quiescent currents about one third of those associated with the MC1741C (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

Features

- Short Circuit Protected Outputs
- Class AB Output Stage for Minimal Crossover Distortion
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 36 V
- Split Supply Operation: ± 1.5 V to ± 18 V
- Low Input Bias Currents: 500 nA Max
- Four Amplifiers Per Package
- Internally Compensated
- Similar Performance to Popular MC1741C
- Industry Standard Pin-outs
- ESD Diodes Added for Increased Ruggedness
- Pb-Free Packages are Available

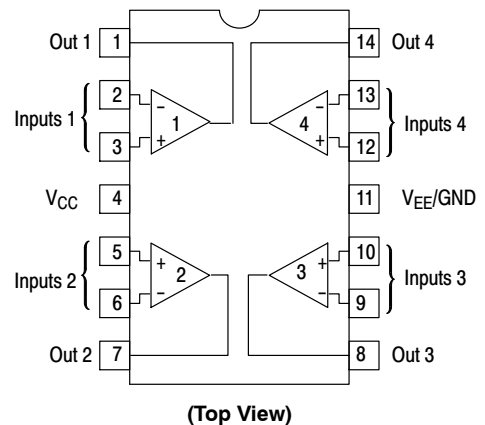


SOIC-14
D SUFFIX
CASE 751A

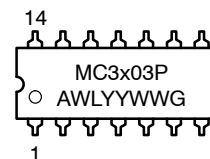
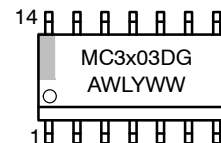


PDIP-14
P SUFFIX
CASE 646

PIN CONNECTIONS



MARKING DIAGRAMS



x = 3 or 4
A = Assembly Location
WL = Wafer Lot
YY, Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 8.

MC3403, MC3303

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{CC} V_{CC}, V_{EE}	Power Supply Voltages Single Supply Split Supplies	36 ± 18	Vdc
V_{IDR}	Input Differential Voltage Range (Note 1)	± 36	Vdc
V_{ICR}	Input Common Mode Voltage Range (Notes 1 and 2)	± 18	Vdc
T_{stg}	Storage Temperature Range	-55 to +125	°C
T_A	Operating Ambient Temperature Range MC3303 MC3403	-40 to +85 0 to +70	°C
T_J	Junction Temperature	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Split power supplies.

2. For supply voltages less than ± 18 V, the absolute maximum input voltage is equal to the supply voltage.

MC3403, MC3303

ELECTRICAL CHARACTERISTICS

($V_{CC} = +15\text{ V}$, $V_{EE} = -15\text{ V}$ for MC3403; $V_{CC} = +14\text{ V}$, $V_{EE} = \text{GND}$ for MC3303 $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Symbol	Characteristic	MC3403			MC3303			Unit
		Min	Typ	Max	Min	Typ	Max	
V_{IO}	Input Offset Voltage $T_A = T_{\text{high}}$ to T_{low} (Note 3)	–	2.0	10	–	2.0	8.0	mV
		–	–	12	–	–	10	
I_{IO}	Input Offset Current $T_A = T_{\text{high}}$ to T_{low}	–	30	50	–	30	75	nA
		–	–	200	–	–	250	
A_{VOL}	Large Signal Open Loop Voltage Gain $V_O = \pm 10\text{ V}$, $R_L = 2.0\text{ k}\Omega$ $T_A = T_{\text{high}}$ to T_{low}	20	200	–	20	200	–	V/mV
		15	–	–	15	–	–	
I_{IB}	Input Bias Current $T_A = T_{\text{high}}$ to T_{low}	–	–200	–500	–	–200	–500	nA
		–	–	–800	–	–	–1000	
z_o	Output Impedance $f = 20\text{ Hz}$	–	75	–	–	75	–	Ω
z_i	Input Impedance $f = 20\text{ Hz}$	0.3	1.0	–	0.3	1.0	–	M Ω
V_O	Output Voltage Range $R_L = 10\text{ k}\Omega$ $R_L = 2.0\text{ k}\Omega$ $R_L = 2.0\text{ k}\Omega$, $T_A = T_{\text{high}}$ to T_{low}	± 12 ± 10 ± 10	± 13.5 ± 13 –	– – –	12 10 10	12.5 12 –	– – –	V
V_{ICR}	Input Common Mode Voltage Range	+13 V – V_{EE}	+13 V – V_{EE}	–	+12 V – V_{EE}	+12.5 V – V_{EE}	–	V
CMR	Common Mode Rejection $R_S \leq 10\text{ k}\Omega$	70	90	–	70	90	–	dB
I_{CC} , I_{EE}	Power Supply Current ($V_O = 0$) $R_L = \infty$	–	2.8	7.0	–	2.8	7.0	mA
I_{SC}	Individual Output Short-Circuit Current (Note 4)	± 10	± 20	± 45	± 10	± 30	± 45	mA
PSRR+	Positive Power Supply Rejection Ratio	–	30	150	–	30	150	$\mu\text{V/V}$
PSRR–	Negative Power Supply Rejection Ratio	–	30	150	–	30	150	$\mu\text{V/V}$
$\Delta I_{IO}/\Delta T$	Average Temperature Coefficient of Input Offset Current $T_A = T_{\text{high}}$ to T_{low}	–	50	–	–	50	–	pA/ $^\circ\text{C}$
$\Delta V_{IO}/\Delta T$	Average Temperature Coefficient of Input Offset Voltage $T_A = T_{\text{high}}$ to T_{low}	–	10	–	–	10	–	$\mu\text{V}/^\circ\text{C}$
BWp	Power Bandwidth $A_V = 1$, $R_L = 10\text{ k}\Omega$, $V_O = 20\text{ V(p-p)}$, THD = 5%	–	9.0	–	–	9.0	–	kHz
BW	Small-Signal Bandwidth $A_V = 1$, $R_L = 10\text{ k}\Omega$, $V_O = 50\text{ mV}$	–	1.0	–	–	1.0	–	MHz
SR	Slew Rate $A_V = 1$, $V_i = -10\text{ V}$ to $+10\text{ V}$	–	0.6	–	–	0.6	–	V/ μs
t_{TLH}	Rise Time $A_V = 1$, $R_L = 10\text{ k}\Omega$, $V_O = 50\text{ mV}$	–	0.35	–	–	0.35	–	μs
t_{TLH}	Fall Time $A_V = 1$, $R_L = 10\text{ k}\Omega$, $V_O = 50\text{ mV}$	–	0.35	–	–	0.35	–	μs
os	Overshoot $A_V = 1$, $R_L = 10\text{ k}\Omega$, $V_O = 50\text{ mV}$	–	20	–	–	20	–	%
ϕ_m	Phase Margin $A_V = 1$, $R_L = 2.0\text{ k}\Omega$, $V_O = 200\text{ pF}$	–	60	–	–	60	–	$^\circ$
–	Crossover Distortion ($V_{in} = 30\text{ mVpp}$, $V_{out} = 2.0\text{ Vpp}$, $f = 10\text{ kHz}$)	–	1.0	–	–	1.0	–	%

3. MC3303: $T_{\text{low}} = -40^\circ\text{C}$, $T_{\text{high}} = +85^\circ\text{C}$, MC3403: $T_{\text{low}} = 0^\circ\text{C}$, $T_{\text{high}} = +70^\circ\text{C}$

4. Not to exceed maximum package power dissipation.

MC3403, MC3303

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5.0\text{ V}$, $V_{EE} = \text{GND}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Symbol	Characteristic	MC3403			MC3303			Unit
		Min	Typ	Max	Min	Typ	Max	
V_{IO}	Input Offset Voltage	–	2.0	10	–	–	10	mV
I_{IO}	Input Offset Current	–	30	50	–	–	75	nA
I_{IB}	Input Bias Current	–	–200	–500	–	–	–500	nA
A_{VOL}	Large Signal Open Loop Voltage Gain $R_L = 2.0\text{ k}\Omega$	10	200	–	10	200	–	V/mV
PSRR	Power Supply Rejection Ratio	–	–	150	–	–	150	$\mu\text{V/V}$
V_{OR}	Output Voltage Range (Note 5) $R_L = 10\text{ k}\Omega$, $V_{CC} = 5.0\text{ V}$ $R_L = 10\text{ k}\Omega$, $5.0 \leq V_{CC} \leq 30\text{ V}$	3.3 $V_{CC}-2.0$	3.5 $V_{CC}-1.7$	– –	3.3 $V_{CC}-2.0$	3.5 $V_{CC}-1.7$	– –	V_{pp}
I_{CC}	Power Supply Current	–	2.5	7.0	–	2.5	7.0	mA
CS	Channel Separation $f = 1.0\text{ kHz to } 20\text{ kHz}$ (Input Referenced)	–	–120	–	–	–120	–	dB

5. Output will swing to ground with a $10\text{ k}\Omega$ pull down resistor.

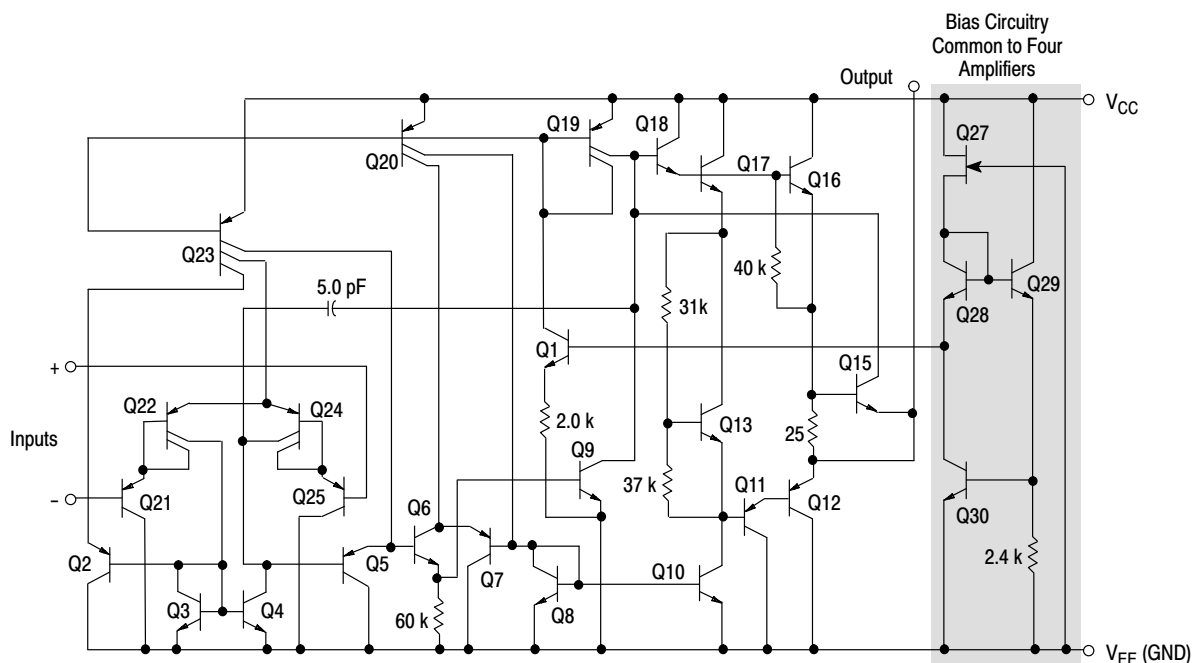


Figure 1. Representative Schematic Diagram
(1/4 of Circuit Shown)

CIRCUIT DESCRIPTION

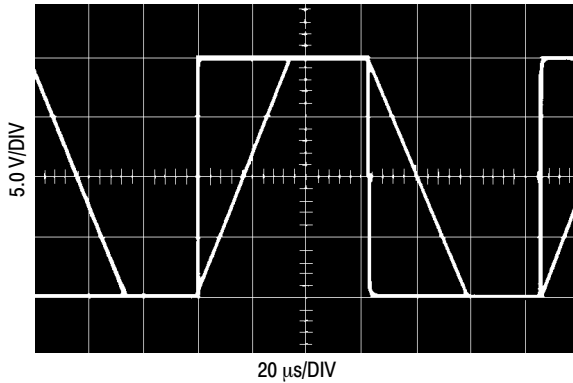


Figure 2. Inverter Pulse Response

The MC3403/3303 is made using four internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input device Q24 and Q22 with input buffer transistors Q25 and Q21 and the differential to single ended converter Q3 and Q4. The first

stage performs not only the first stage gain function but also performs the level shifting and Transconductance reduction functions. By reducing the Transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The Transconductance reduction is accomplished by splitting the collectors of Q24 and Q22. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

The output stage is unique because it allows the output to swing to ground in single supply operation and yet does not exhibit any crossover distortion in split supply operation. This is possible because Class AB operation is utilized.

Each amplifier is biased from an internal voltage regulator which has a low temperature coefficient, thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

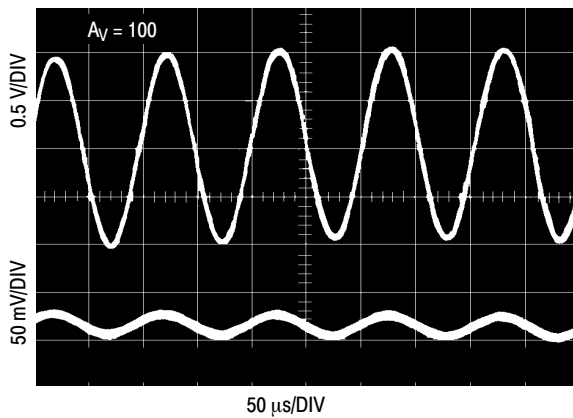


Figure 3. Sine Wave Response

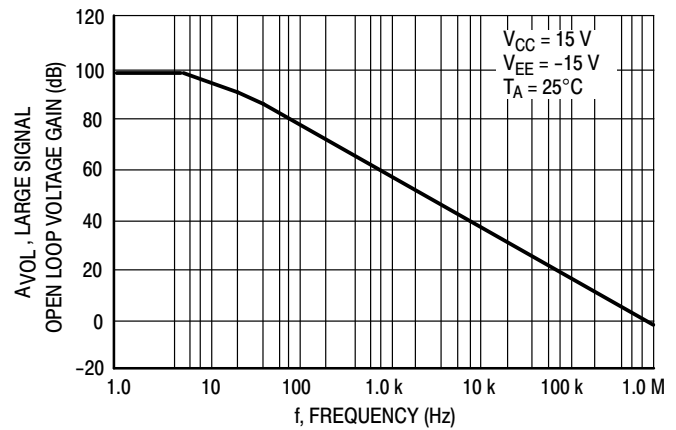


Figure 4. Open Loop Frequency Response

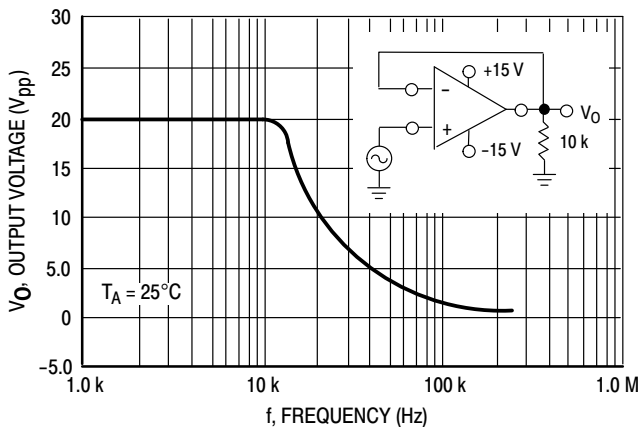


Figure 5. Power Bandwidth

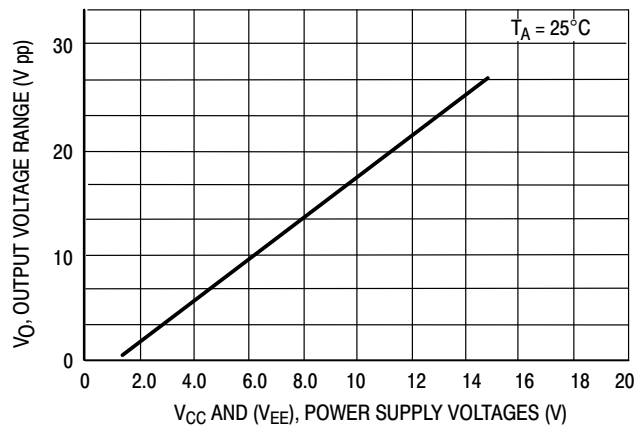


Figure 6. Output Swing versus Supply Voltage

MC3403, MC3303

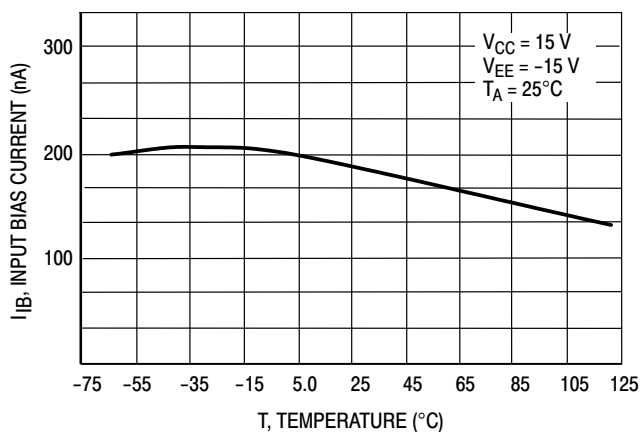


Figure 7. Input Bias Current versus Temperature

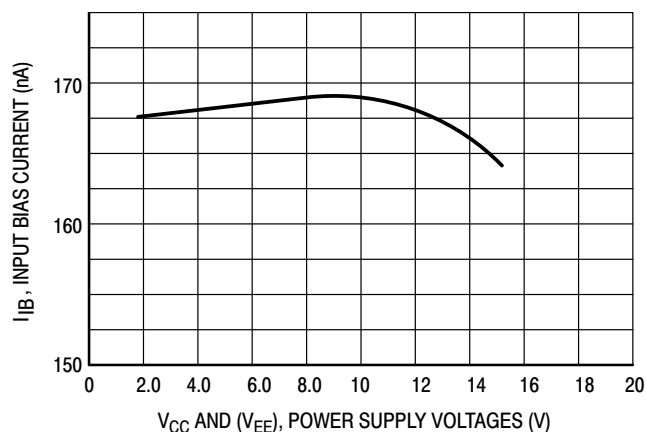


Figure 8. Input Bias Current versus Supply Voltage

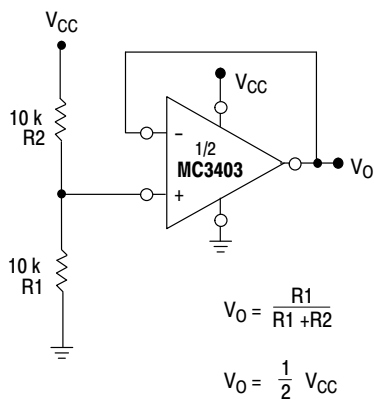


Figure 9. Voltage Reference

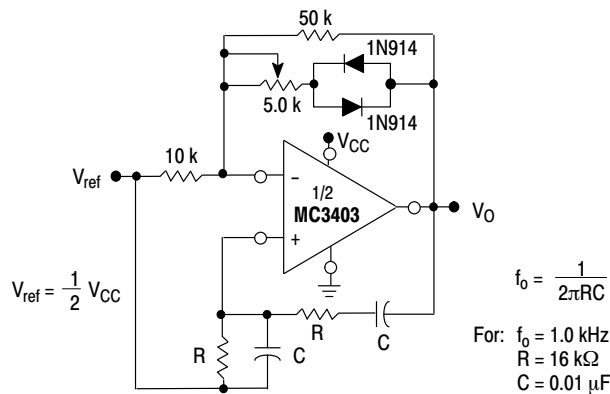


Figure 10. Wien Bridge Oscillator

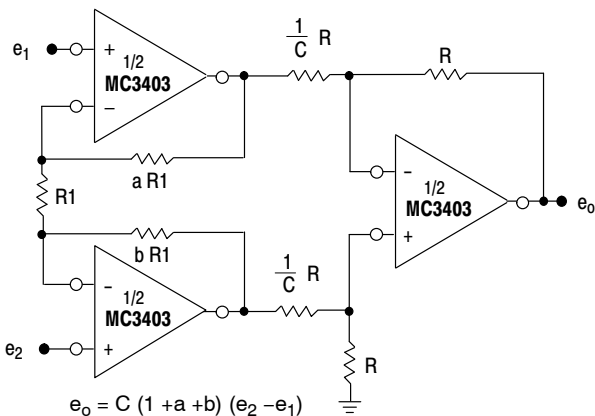


Figure 11. High Impedance Differential Amplifier

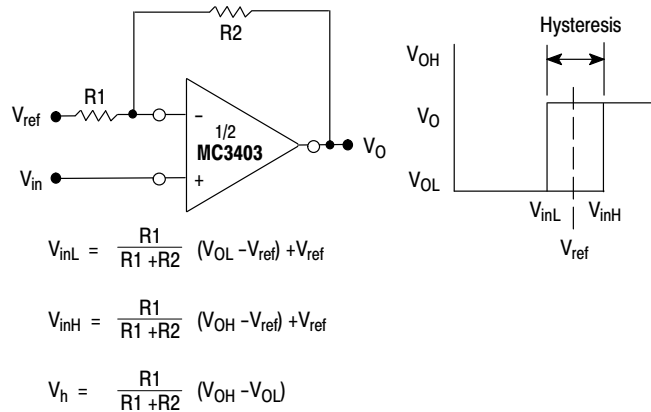


Figure 12. Comparator with Hysteresis

MC3403, MC3303

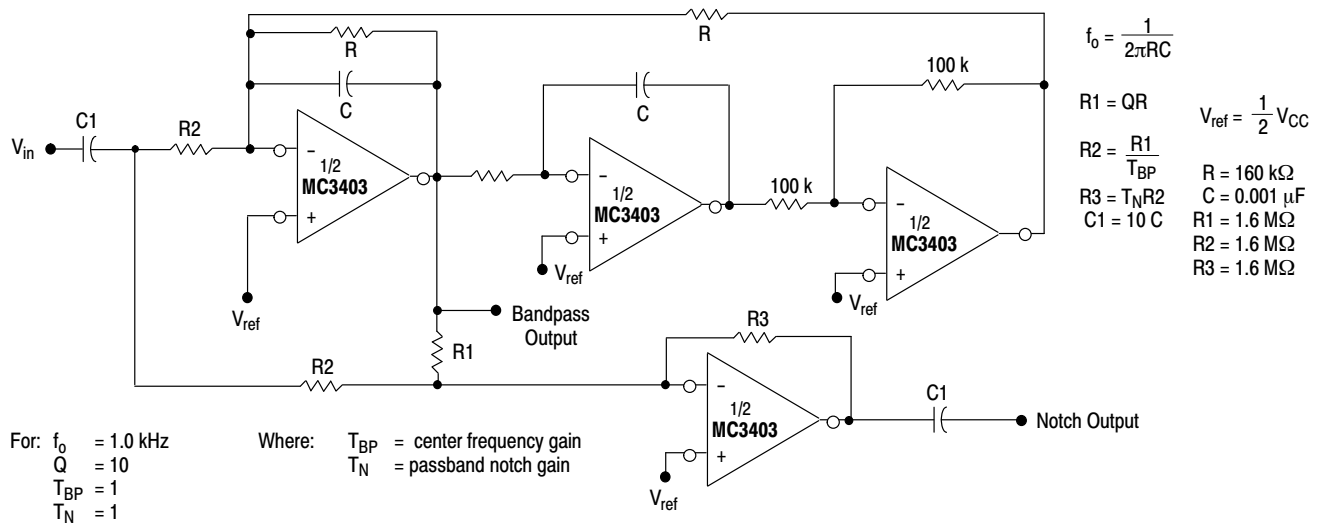


Figure 13. Bi-Quad Filter

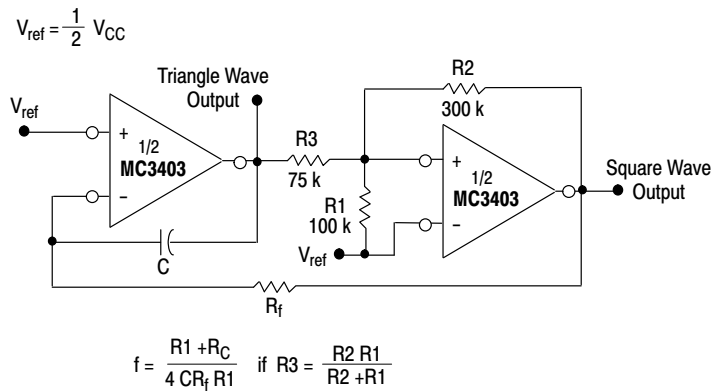
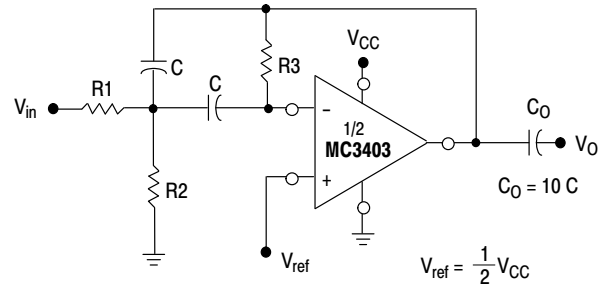


Figure 14. Function Generator



Given: f_0 = center frequency
 $A(f_0)$ = gain at center frequency

Choose value f_0 , C

$$\text{Then: } R3 = \frac{Q}{\pi f_0 C} \quad R1 = \frac{R3}{2 A(f_0)} \quad R2 = \frac{R1 R5}{4 Q^2 R1 - R5}$$

For less than 10% error from operational amplifier where f_0 and BW are expressed in Hz.

If source impedance varies, filter may be preceded by voltage follower buffer to stabilize filter parameters.

Figure 15. Multiple Feedback Bandpass Filter

MC3403, MC3303

ORDERING INFORMATION

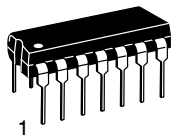
Device	Package	Shipping [†]
MC3303DR2G	SOIC-14 (Pb-Free)	2,500 Tape & Reel
MC3403DR2G	SOIC-14 (Pb-Free)	2,500 Tape & Reel

DISCONTINUED (Note 6)

MC3303D	SOIC-14	55 Units / Rail
MC3303DG	SOIC-14 (Pb-Free)	
MC3303DR2	SOIC-14	2,500 Tape & Reel
MC3303P	PDIP-14	25 Units / Rail
MC3303PG	PDIP-14 (Pb-Free)	
MC3403D	SOIC-14	55 Units / Rail
MC3403DG	SOIC-14 (Pb-Free)	
MC3403DR2	SOIC-14	2,500 Tape & Reel
MC3403P	PDIP-14	25 Units / Rail
MC3403PG	PDIP-14 (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

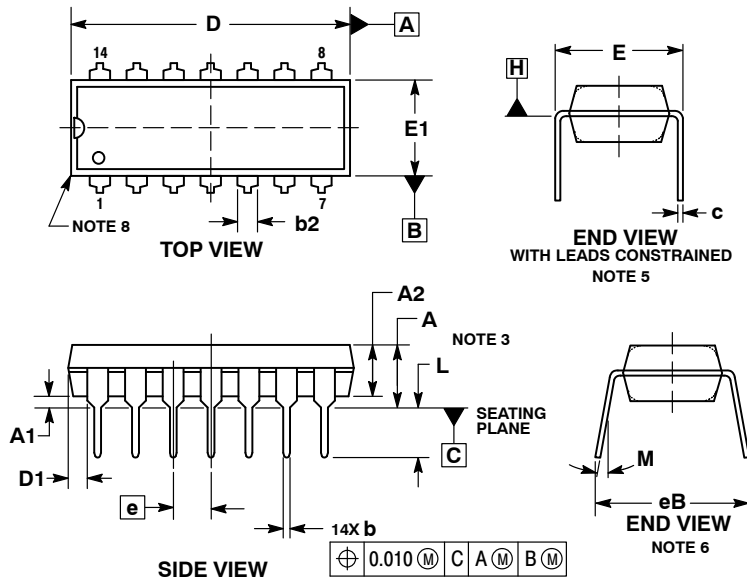
6. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.



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PDIP-14
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ISSUE S

DATE 22 APR 2015



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.
4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.
6. DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.
7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.
8. PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	---	0.210	---	5.33
A1	0.015	---	0.38	---
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060 TYP 1.52 TYP			
C	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005	---	0.13	---
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
eB	---	0.430	---	10.92
L	0.115	0.150	2.92	3.81
M	---	10°	---	10°

GENERIC
MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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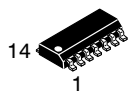
PDIP-14
CASE 646-06
ISSUE S

DATE 22 APR 2015

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. DRAIN 2. SOURCE 3. GATE 4. NO CONNECTION 5. GATE 6. SOURCE 7. DRAIN 8. DRAIN 9. SOURCE 10. GATE 11. NO CONNECTION 12. GATE 13. SOURCE 14. DRAIN
STYLE 5: PIN 1. GATE 2. DRAIN 3. SOURCE 4. NO CONNECTION 5. SOURCE 6. DRAIN 7. GATE 8. GATE 9. DRAIN 10. SOURCE 11. NO CONNECTION 12. SOURCE 13. DRAIN 14. GATE	STYLE 6: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 7: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 8: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 9: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE	STYLE 10: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 12: PIN 1. COMMON CATHODE 2. COMMON ANODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. COMMON ANODE 7. COMMON CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. ANODE/CATHODE 14. ANODE/CATHODE

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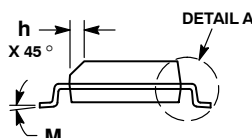
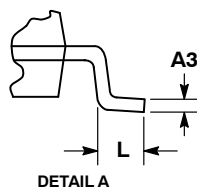
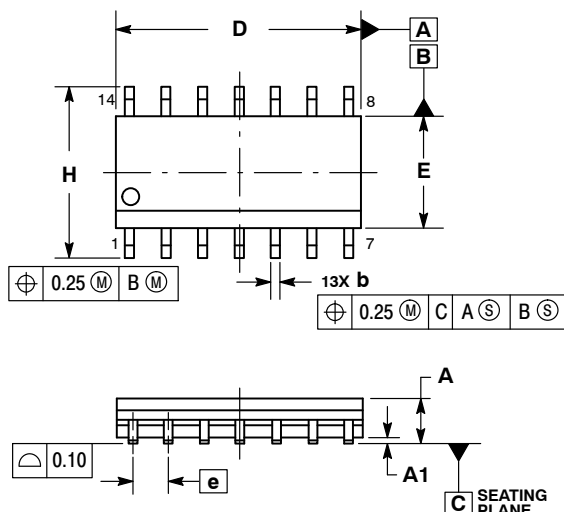
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ISSUE L

DATE 03 FEB 2016

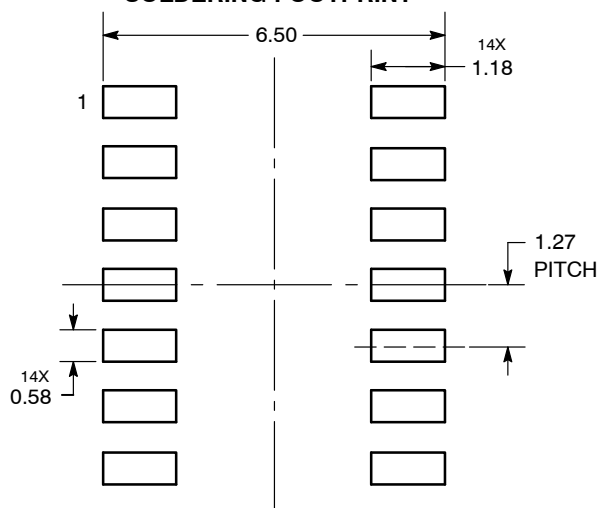


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

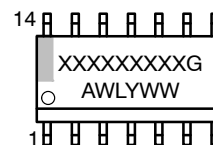
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-14
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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